

Born–Oppenheimer (single-surface) and its TD breakdown

Part I: Single-surface BO from $H = H_{\text{electron}} + H_{\text{ion}}$

Hamiltonian split. Write the full Hamiltonian as a sum of an *electronic* part (acts on \mathbf{r} ; depends on \mathbf{R} only as parameters) and an *ionic* part (acts on \mathbf{R}):

$$\begin{aligned} H &= H_{\text{electron}}(\mathbf{r}; \mathbf{R}) + H_{\text{ion}}(\mathbf{R}, \{\nabla_A\}), \\ H_{\text{electron}}(\mathbf{r}; \mathbf{R}) &= T_e + V_{ee} + V_{e-ion}(\mathbf{R}), \\ H_{\text{ion}}(\mathbf{R}, \{\nabla_A\}) &= T_{\text{ion}} + V_{ion-ion}(\mathbf{R}), \quad T_{\text{ion}} = - \sum_A \frac{\hbar^2}{2M_A} \nabla_A^2. \end{aligned}$$

Product ansatz and electronic ground state. For each fixed \mathbf{R} , define the electronic ground state

$$H_{\text{electron}}(\mathbf{r}; \mathbf{R}) \phi_0(\mathbf{r}; \mathbf{R}) = E_0(\mathbf{R}) \phi_0(\mathbf{r}; \mathbf{R}), \quad \langle \phi_0(\mathbf{R}) | \phi_0(\mathbf{R}) \rangle_{\mathbf{r}} = 1.$$

Assume the total wavefunction is a single-surface product

$$\Psi(\mathbf{r}, \mathbf{R}) = \chi(\mathbf{R}) \phi_0(\mathbf{r}; \mathbf{R}).$$

Action of H_{electron} and H_{ion} . Since H_{electron} acts only on \mathbf{r} ,

$$\langle \phi_0 | H_{\text{electron}} | \Psi \rangle_{\mathbf{r}} = E_0(\mathbf{R}) \chi(\mathbf{R}).$$

The ion–ion potential multiplies the product:

$$\langle \phi_0 | V_{ion-ion} | \Psi \rangle_{\mathbf{r}} = V_{ion-ion}(\mathbf{R}) \chi(\mathbf{R}).$$

The nuclear kinetic energy acts on both χ and the \mathbf{R} -dependence of ϕ_0 ; using $\nabla_A^2(\chi\phi_0) = (\nabla_A^2\chi)\phi_0 + 2(\nabla_A\chi)\cdot(\nabla_A\phi_0) + \chi(\nabla_A^2\phi_0)$ and defining the derivative couplings

$$\mathbf{D}_A(\mathbf{R}) \equiv \langle \phi_0 | \nabla_A \phi_0 \rangle_{\mathbf{r}}, \quad \tau_A(\mathbf{R}) \equiv \langle \phi_0 | \nabla_A^2 \phi_0 \rangle_{\mathbf{r}},$$

one finds the *exact* single-surface nuclear equation

$$-\sum_A \frac{\hbar^2}{2M_A} \left[\nabla_A^2 \chi + 2 \mathbf{D}_A \cdot \nabla_A \chi + \tau_A \chi \right] + \underbrace{[E_0(\mathbf{R}) + V_{ion-ion}(\mathbf{R})]}_{U_{\text{BO}}(\mathbf{R})} \chi(\mathbf{R}) = E \chi(\mathbf{R}).$$

Born–Oppenheimer (leading order in $1/M$). The terms proportional to \mathbf{D}_A and τ_A originate from T_{ion} acting on the \mathbf{R} -dependence of ϕ_0 and are $\mathcal{O}(1/M_A)$ (nonadiabatic couplings). Neglecting them gives the standard BO nuclear equation on the BO surface $U_{\text{BO}}(\mathbf{R})$:

$$\left[-\sum_A \frac{\hbar^2}{2M_A} \nabla_A^2 + U_{\text{BO}}(\mathbf{R}) \right] \chi(\mathbf{R}) = E \chi(\mathbf{R}), \quad U_{\text{BO}}(\mathbf{R}) \equiv E_0(\mathbf{R}) + V_{ion-ion}(\mathbf{R}).$$

Part II: Why one electronic state is not exact (TD nonadiabatic couplings)

Born–Huang (multi-surface) expansion. Expand the total wavefunction in the full adiabatic electronic basis:

$$\Psi(\mathbf{r}, \mathbf{R}, t) = \sum_n \chi_n(\mathbf{R}, t) \phi_n(\mathbf{r}; \mathbf{R}), \quad H_{\text{electron}}(\mathbf{r}; \mathbf{R}) \phi_n = E_n(\mathbf{R}) \phi_n.$$

Insert into $i\hbar \partial_t \Psi = H\Psi$ and project onto ϕ_m . Defining the *nonadiabatic derivative couplings*

$$\mathbf{D}_{mn}^A(\mathbf{R}) \equiv \langle \phi_m(\mathbf{R}) | \nabla_A \phi_n(\mathbf{R}) \rangle_{\mathbf{r}}, \quad \tau_{mn}^A(\mathbf{R}) \equiv \langle \phi_m(\mathbf{R}) | \nabla_A^2 \phi_n(\mathbf{R}) \rangle_{\mathbf{r}},$$

one obtains the coupled nuclear equations

$$\begin{aligned} i\hbar \partial_t \chi_m(\mathbf{R}, t) &= \left[- \sum_A \frac{\hbar^2}{2M_A} \nabla_A^2 + E_m(\mathbf{R}) \right] \chi_m(\mathbf{R}, t) \\ &\quad - \sum_n \sum_A \frac{\hbar^2}{M_A} \mathbf{D}_{mn}^A(\mathbf{R}) \cdot \nabla_A \chi_n(\mathbf{R}, t) - \sum_n \sum_A \frac{\hbar^2}{2M_A} \tau_{mn}^A(\mathbf{R}) \chi_n(\mathbf{R}, t). \end{aligned}$$

The **off-diagonal** terms ($m \neq n$) *mix* electronic channels: even if initially $\chi_{n>0} = 0$, they generate population in excited states during time evolution.

Adiabatic criterion (when single-surface BO is OK). Using Hellmann–Feynman for $m \neq n$, $\mathbf{D}_{mn}^A = \frac{\langle \phi_m | \nabla_A H_{\text{electron}} | \phi_n \rangle}{E_n - E_m}$, so couplings grow when the electronic gap $|E_n - E_m|$ is small (avoided crossings, conical intersections). A rough adiabaticity condition is that the mixing rate be small compared to the gap:

$$|\dot{\mathbf{R}} \cdot \mathbf{d}_{mn}| \ll |E_n(\mathbf{R}) - E_m(\mathbf{R})|/\hbar, \quad \mathbf{d}_{mn} \equiv \sum_A \mathbf{D}_{mn}^A \dot{\mathbf{R}}_A,$$

so slow nuclear motion and large gaps suppress transitions. Otherwise, multi-surface dynamics is necessary (Landau–Zener transitions provide a useful two-level estimate).

Bottom line. The single-surface product $\Psi = \chi(\mathbf{R}, t) \phi_0(\mathbf{r}; \mathbf{R})$ is an approximation. In real time evolution, the off-diagonal nonadiabatic couplings inevitably transfer amplitude to excited electronic states unless the motion is perfectly adiabatic (heavy nuclei, slow motion, large gaps). Near degeneracies (e.g., conical intersections) a multi-state treatment or a diabatic representation is essential.